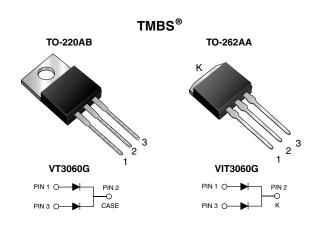




Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.40 \text{ V}$ at $I_F = 5 \text{ A}$



| PRIMARY CHARACTERISTICS | | | | | |
|---|----------|--|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | | |
| V _{RRM} | 60 V | | | | |
| I _{FSM} | 150 A | | | | |
| V _F at I _F = 15 A | 0.61 V | | | | |
| T _J max. | 150 °C | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

High efficiency operation
Co

Solder bath temperature 275 °C max. 10 s, per JESD 22-B106

- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and

AEC-Q101 qualified **Terminals:** Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|------------|-----------------------------------|---------------|----------|------|--|
| PARAMETER | | SYMBOL | VT3060G | VIT3060G | UNIT | |
| Maximum repetitive peak reverse voltage | | V_{RRM} | 60 | | V | |
| Maximum average forward rectified current (fig. 1) | per device | | 30 | | А | |
| | per diode | I _{F(AV)} | 15 | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | | I _{FSM} | 150 | | А | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | | V/µs | |
| Operating junction and storage temperature range | | T _J , T _{STG} | - 55 to + 150 | | °C | |

VT3060G, VIT3060G

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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|------------------------|---|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | I _F = 7.5 A T _A = 25 °C | V _F ⁽¹⁾ | 0.49 | - | - V | |
| | I _F = 7.5 A | | | 0.53 | - | | |
| | I _F = 15 A | | | 0.65 | 0.73 | | |
| | I _F = 5 A | T _A = 125 °C | | 0.40 | - | | |
| | I _F = 7.5 A | | | 0.46 | - | | |
| | I _F = 15 A | | | 0.61 | 0.69 | | |
| Reverse current per diode | V _R = 60 V | T _A = 25 °C | I _R ⁽²⁾ | - | 850 | μΑ | |
| | | T _A = 125 °C | | 14 | 40 | mA | |

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|------------------|---------|----------|------|
| PARAMETER | | SYMBOL | VT3060G | VIT3060G | UNIT |
| Typical thermal resistance | per diode | В | 3.2 | | °C/W |
| | per device | $ R_{\theta JC}$ | 1.9 | | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|--------------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-220AB | VT3060G-M3/4W | 1.88 | 4W | 50/tube | Tube | |
| TO-262AA | VIT3060G-M3/4W | 1.45 | 4W | 50/tube | Tube | |
| TO-220AB | VT3060GHM3/4W (1) | 1.88 | 4W | 50/tube | Tube | |
| TO-262AA | VIT3060GHM3/4W (1) | 1.45 | 4W | 50/tube | Tube | |

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

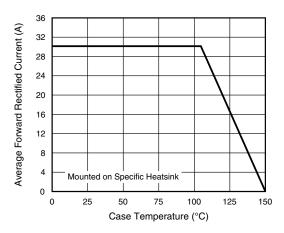


Fig. 1 - Maximum Forward Current Derating Curve

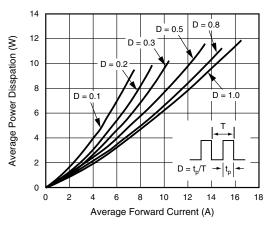


Fig. 2 - Forward Power Dissipation Characteristics

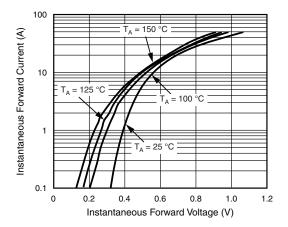


Fig. 3 - Typical Instantaneous Forward Characteristics

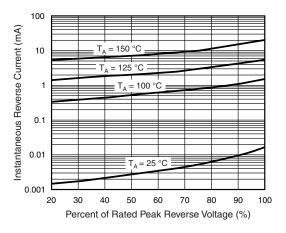


Fig. 4 - Typical Reverse Characteristics

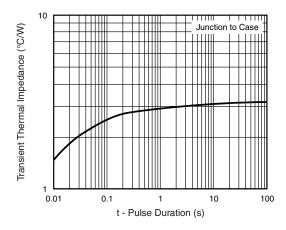


Fig. 5 - Typical Transient Thermal Impedance

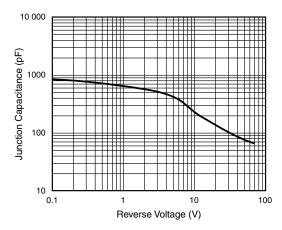


Fig. 6 - Typical Junction Capacitance

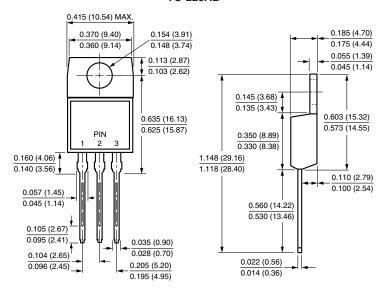
VT3060G, VIT3060G

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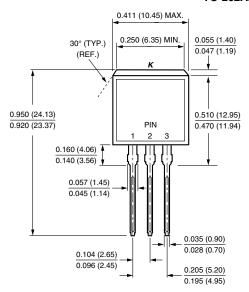


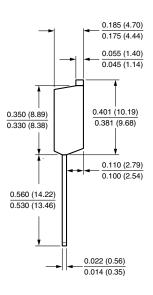
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA









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